## NSN 5962-01-381-0396

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View Online at https://aerobasegroup.com/nsn/5962-01-381-0396 **Body Length:** 0.740 inches **Body Width:** 0.420 inches **Body Height:** 0.130 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 26 input **Case Outline Source And Designator:** F-12 mil-m-38510 **Current Rating Per Characteristic:** 80.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 6.25 volts power source **Capitance Rating Per Characteristic:** 10.00 input picofarads and 10.00 output picofarads **Time Rating Per Chacteristic:** 150.00 nanoseconds access **Memory Device Type: Eeprom Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 flat leads Shelf Life:

N/a

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Demilitarization:

No

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